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# PN200A / MMBT200 PNP General-Purpose Amplifier

# Description

This device is designed for general-purpose amplifier applications at collector currents to 300 mA. Sourced from Process 68.



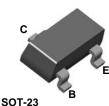


Figure 2. MMBT200 Device Package

## Figure 1. PN200A Device Package

## **Ordering Information**

Part Number	Marking	Package	Packing Method	
PN200A	PN200A	TO-92 3L	Bulk	
MMBT200	N2	SOT-23 3L	Tape and Reel	

# Absolute Maximum Ratings<sup>(1),(2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	-45	V
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V
Ι <sub>C</sub>	Collector Current - Continuous	-500	mA
T <sub>J,</sub> T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

### Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or lowduty cycle operations.

# **Thermal Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Ma	Unit	
	i didineter	PN200A <sup>(3)</sup>	MMBT200 <sup>(4)</sup>	Onic
р	Total Device Dissipation	625	350	mW
PD	Derate Above 25°C	5.0	2.8	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

### Notes:

3. PCB size: FR-4 76 x 114 x 1.57 mm<sup>3</sup> (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

4. Device mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.

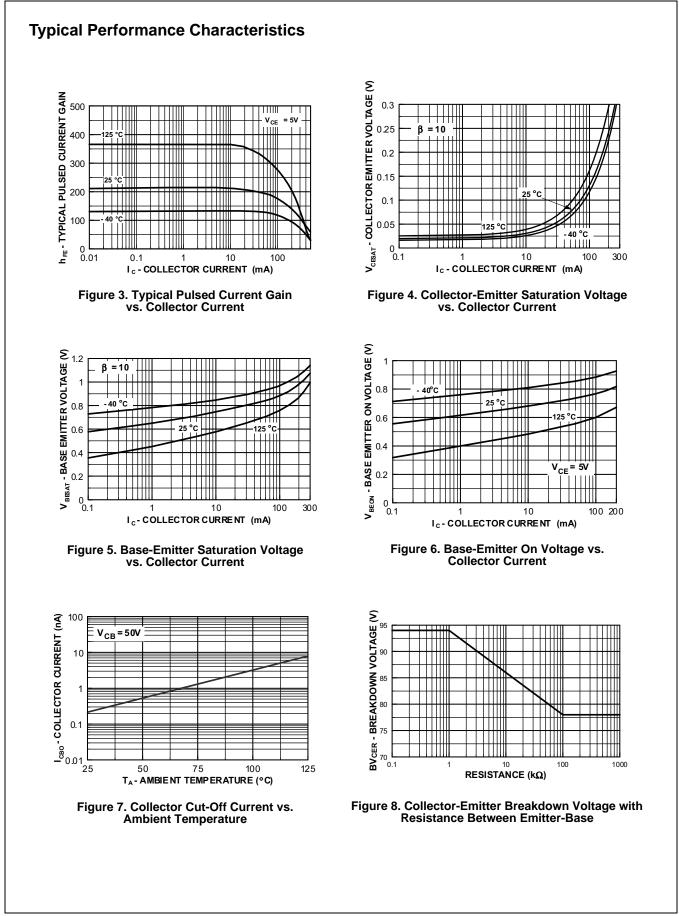
# **Electrical Characteristics**

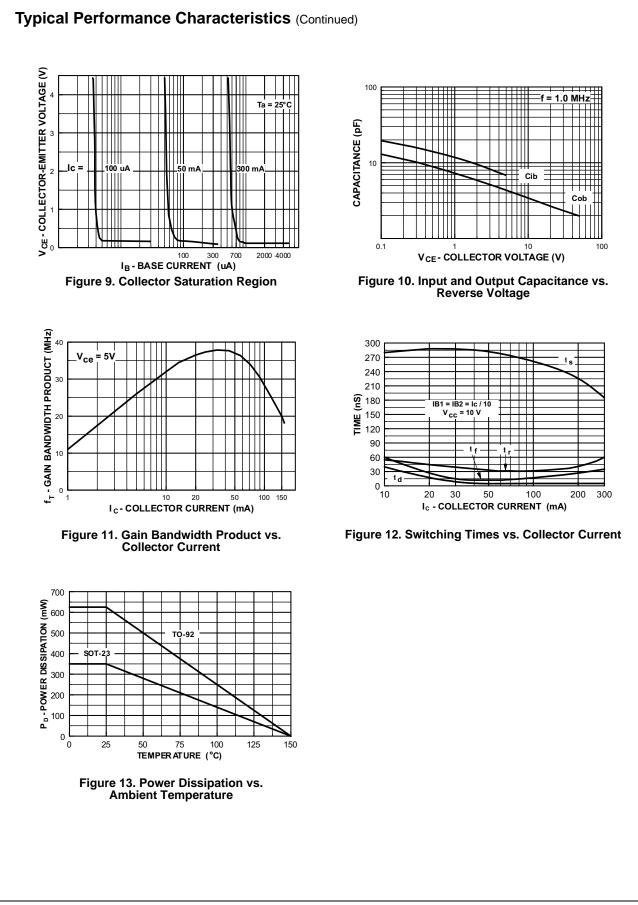
Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

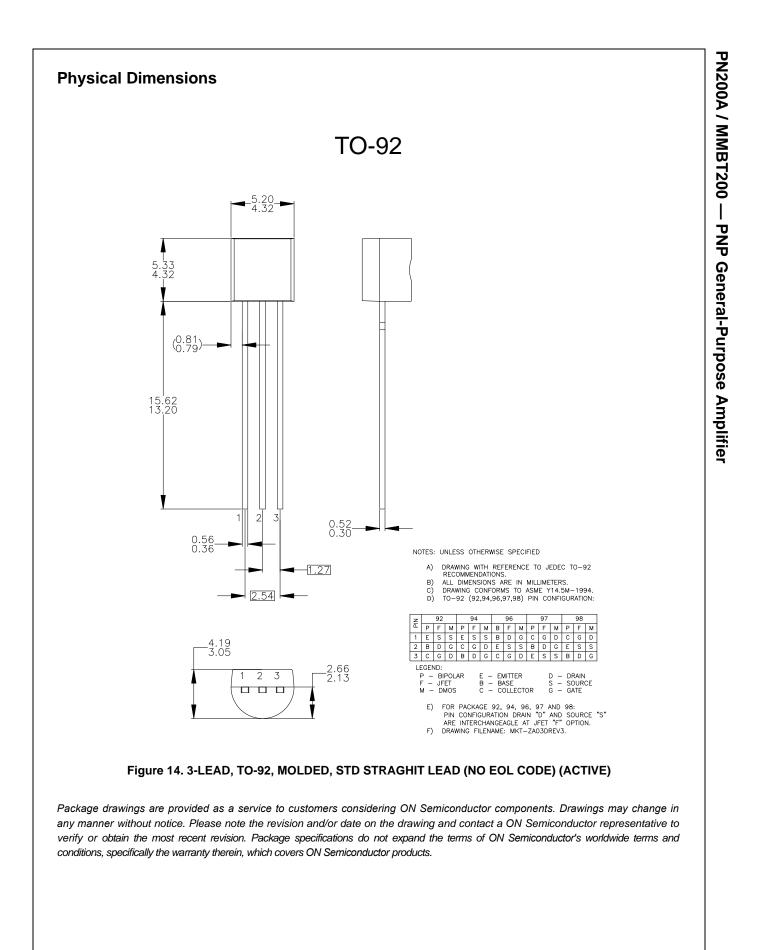
Symbol	Parameter	Conditions		Min.	Max.	Unit
Off Charact	eristics					
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = -10 \ \mu \text{A}, \ I_{\rm B} = 0$		-60		V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage <sup>(5)</sup>	$I_{\rm C} = -1.0 \text{ mA}, I_{\rm E} = 0$		-45		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = -10 \ \mu A, \ I_{C} = 0$		-6.0		V
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = -50 \text{ V}, \text{ I}_{E} = 0$			-50	nA
I <sub>CES</sub>	Collector Cut-Off Current	$V_{CE} = -40 \text{ V}, \text{ I}_{E} = 0$			-50	nA
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = -4.0 \text{ V}, I_{C} = 0$			-50	nA
On Charact	eristics					
	DC Current Gain	I <sub>C</sub> = -100 μA, V <sub>CE</sub> = -1.0 V	MMBT200	80		
			PN200A	240		
		I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -1.0 V	MMBT200	100	450	
h			PN200A	300	600	
h <sub>FE</sub>		$I_{C} = -100 \text{ mA},$ $V_{CE} = -1.0 \text{ V}^{(5)}$	PN200A	100		
		$I_{\rm C}$ = -150 mA, V <sub>CE</sub> = -5.0 V <sup>(5)</sup>	MMBT200	100	350	
			PN200A	100		
)/ (aat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -10 mA, I <sub>B</sub> = -1.0 mA			-0.2	V
V <sub>CE</sub> (sat)		$I_{\rm C}$ = -200 mA, $I_{\rm B}$ = -20 mA <sup>(5)</sup>			-0.4	
	Base-Emitter Saturation	I <sub>C</sub> = -10 mA, I <sub>B</sub> = -1.0 mA			-0.85	v
V <sub>BE</sub> (sat)	Voltage	$I_{\rm C}$ = -200 mA, $I_{\rm B}$ = -20 mA <sup>(5)</sup>			-1.00	
Small Signa	al Characteristics					•
f <sub>T</sub>	Current Gain - Bandwidth Product	$V_{CE} = -20 \text{ V}, I_{C} = -20 \text{ mA},$		250		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10 V, f = -1.0 MHz			6.0	pF
NF	Noise Figure	$I_{C} = -100 \ \mu\text{A}, \ V_{CE} = -5.0 \ \text{V},$ R <sub>G</sub> = 2.0 kΩ, f = 1.0 kHz			4.0	dB

### Note:

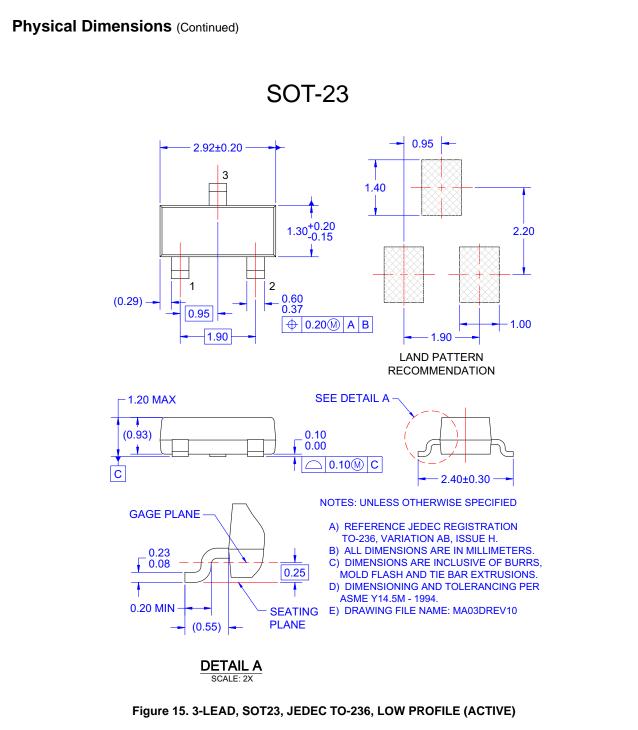
5. Pulse test: pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2.0%.







5



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